TOSHIBA Field Effect Transistor Silicon N Channel Dual Gate MOS Type

3SK207

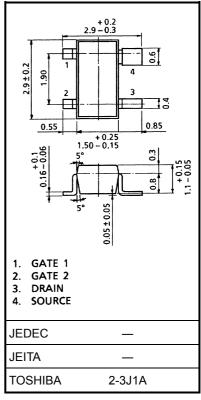
TV Tuner, UHF RF Amplifier Applications

Unit: mm

- Superior cross modulation performance.
- Low reverse transfer capacitance: $C_{rss} = 0.015 pF$ (typ.)
- Low noise figure: NF = 1.9dB (typ.)

Maximum Ratings (Ta = 25°C)

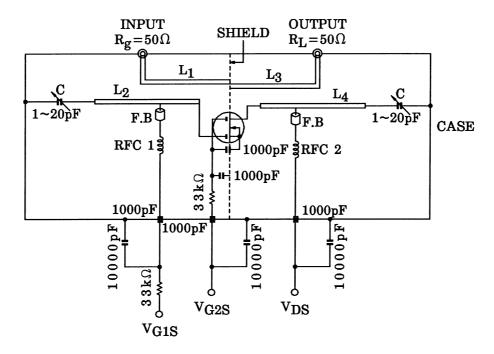
| Characteristics | Symbol | Rating | Unit |
|---------------------------|------------------|------------|------|
| Drain-source voltage | V_{DS} | 13.5 | V |
| Gate 1-source voltage | V _{G1S} | <u>±</u> 8 | ٧ |
| Gate 2-source voltage | V _{G2S} | <u>±</u> 8 | V |
| Drain current | I _D | 30 | mA |
| Drain power dissipation | PD | 150 | mW |
| Channel temperature | T _{ch} | 125 | °C |
| Storage temperature range | T _{stg} | -55~125 | °C |



Weight: 0.013 g (typ.)

Electrical Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------|------------------------|---|------|-------|------|------|
| Gate 1 leakage current | I _{G1SS} | $V_{DS} = 0$, $V_{G1S} = \pm 6$ V, $V_{G2S} = 0$ | _ | _ | ±50 | nA |
| Gate 2 leakage current | I _{G2SS} | $V_{DS} = 0$, $V_{G1S} = 0$, $V_{G2S} = \pm 6 \text{ V}$ | _ | _ | ±50 | nA |
| Drain-source voltage | V (BR) DSX | $V_{G1S} = -4 \text{ V}, V_{G2S} = -4 \text{ V}$ $I_D = 100 \mu\text{A}$ | 13.5 | _ | | V |
| Drain current | I _{DSS} | $V_{DS} = 6 \text{ V}, V_{G1S} = 0, V_{G2S} = 4.5 \text{ V}$ | 0 | _ | 0.1 | mA |
| Gate 1-source cut-off voltage | V _{G1S} (OFF) | $V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, I_D = 100 \mu A$ | 0 | _ | 1.0 | V |
| Gate 2-source cut-off voltage | V _{G2S} (OFF) | $V_{DS} = 6 \text{ V}, V_{G1S} = 4 \text{ V}, I_D = 100 \mu\text{A}$ | 0.5 | 1.0 | 1.5 | V |
| Forward transfer admittance | Y _{fs} | $V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}$ $I_D = 10 \text{ mA}, f = 1 \text{ kHz}$ | _ | 21.5 | | mS |
| Input capacitance | C _{iss} | V _{DS} = 6 V, V _{G2S} = 4.5 V | 1.0 | 1.6 | 2.4 | pF |
| Reverse transfer capacitance | C _{rss} | I _D = 10 mA, f = 1 MHz | _ | 0.015 | 0.03 | pF |
| Power gain | G _{ps} | $V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}$ | 18 | 19.5 | _ | dB |
| Noise figure | NF | I _D = 10 mA, f = 800 MHz (Figure 1) | _ | 1.9 | 3.0 | dB |



C: Air trimmer TTA25A200A (MURATA Manufacturing. Co., Ltd.)

RFC 1: ϕ 0.35 mm copper wire 3 mm ID, 7 T

RFC 2: ϕ 0.35 mm copper wire 3 mm ID, 10 T

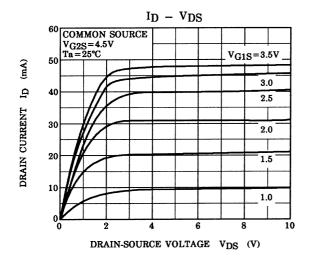
Figure 1 800 MHz G_{ps}, NF Test Circuit

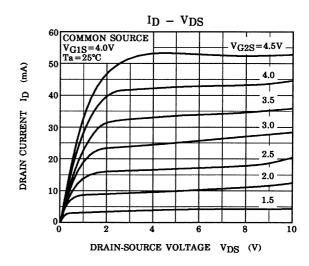
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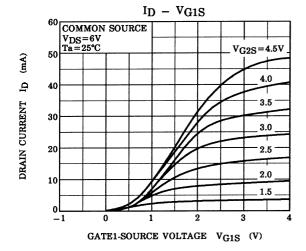
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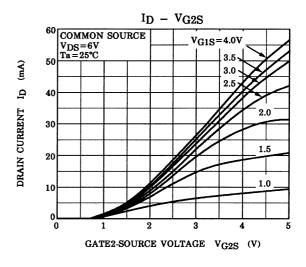


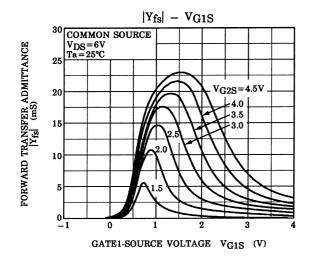
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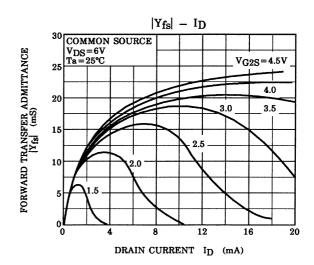


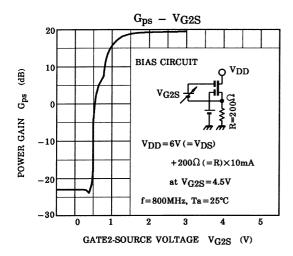


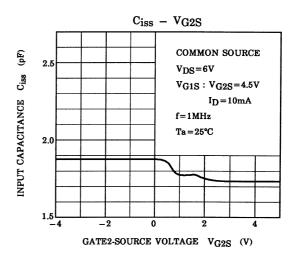


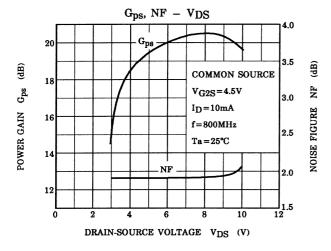


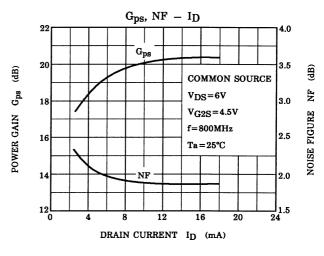


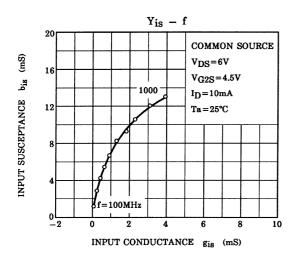


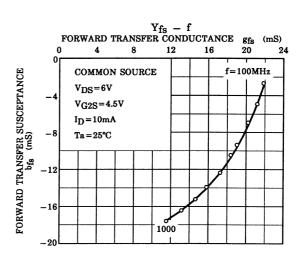




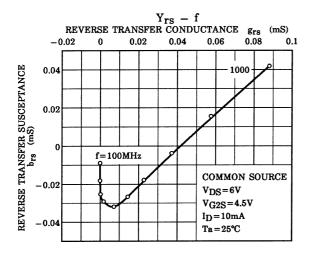


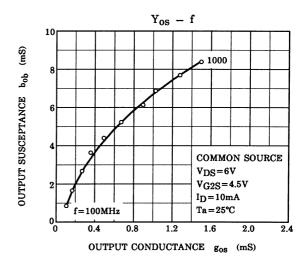


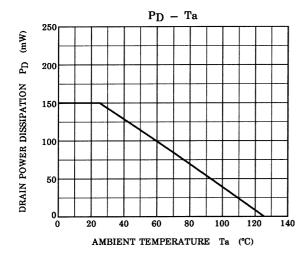




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